

High Accuracy Instrumentation Amplifier

AMP02

FEATURES

Low Offset Voltage: 100 μ V max Low Drift: 2 μ V/°C max Wide Gain Range: 1 to 10,000 High Common-Mode Rejection: 115 dB min High Bandwidth (G = 1000): 200 kHz typ Gain Equation Accuracy: 0.5% max Single Resistor Gain Set Input Overvoltage Protection Low Cost Available in Die Form

APPLICATIONS

Differential Amplifier Strain Gage Amplifier Thermocouple Amplifier RTD Amplifier Programmable Gain Instrumentation Amplifier Medical Instrumentation Data Acquisition Systems

FUNCTIONAL BLOCK DIAGRAM

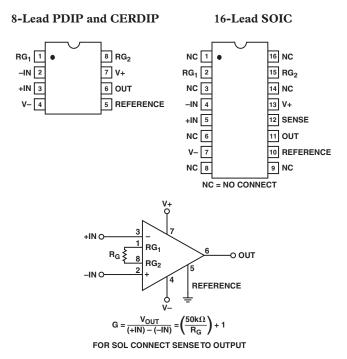


Figure 1. Basic Circuit Connections

GENERAL DESCRIPTION

The AMP02 is the first precision instrumentation amplifier available in an 8-lead package. Gain of the AMP02 is set by a single external resistor and can range from 1 to 10,000. No gain set resistor is required for unity gain. The AMP02 includes an input protection network that allows the inputs to be taken 60 V beyond either supply rail without damaging the device.

Laser trimming reduces the input offset voltage to under 100 μ V. Output offset voltage is below 4 mV, and gain accuracy is better than 0.5% for a gain of 1000. ADI's proprietary thin-film resistor process keeps the gain temperature coefficient under 50 ppm/°C.

Due to the AMP02's design, its bandwidth remains very high over a wide range of gain. Slew rate is over 4 V/ μ s, making the AMP02 ideal for fast data acquisition systems.

A reference pin is provided to allow the output to be referenced to an external dc level. This pin may be used for offset correction or level shifting as required. In the 8-lead package, sense is internally connected to the output.

For an instrumentation amplifier with the highest precision, consult the AMP01 data sheet.

REV. E

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AMP02-SPECIFICATIONS

ELECTRICAL CHARACTERISTICS (@ $V_s = \pm 15 V$, $V_{CM} = 0 V$, $T_A = 25^{\circ}C$, unless otherwise noted.)

| Parameter | Symbol | Conditions | Min | AMP02E Typ | Max | Min | AMP02F Typ | Max | Unit |
|---|--|--|------------|---------------------|---------------|-----------|---------------------|----------------|----------------------------------|
| OFFSET VOLTAGE Input Offset Voltage | | $T_A = 25^{\circ}C$ | | 20 | 100 | | 40 | 200 | μV |
| | V _{IOS} | $-40^{\circ}C \le T_A \le +85^{\circ}C$ | | 50 | 200 | | 100 | 350 | μV |
| Input Offset Voltage Drift Output Offset Voltage | TCV _{IOS} V _{OOS} | $-40^{\circ}C \le T_A \le +85^{\circ}C$ $T_A = 25^{\circ}C$ | | 0.5 1 | $\frac{2}{4}$ | | $\frac{1}{2}$ | 4 8 | μV/°C mV |
| | | $-40^{\circ}C \le T_A \le +85^{\circ}C$ | | 4 | 10 | | 9 | 20 | mV |
| Output Offset Voltage Drift Power Supply Rejection | TCV _{OOS} PSR | $-40^{\circ}C \le T_A \le +85^{\circ}C$ V _S = ±4.8 V to ±18 V | | 50 | 100 | | 100 | 200 | µV/°C |
| | | G = 100, 1000 G = 10 | 115 100 | 125 110 | | 110 95 | 115 100 | | dB dB |
| | | G = 1 | 80 | 90 | | 75 | 80 | | dB |
| | | $V_{S} = \pm 4.8 V \text{ to } \pm 18 V$ $-40^{\circ}C \leq T_{A} \leq +85^{\circ}C$ | | | | | | | |
| | | G = 1000, 100 G = 10 | 110 95 | 120 110 | | 105 90 | 110 95 | | dB dB |
| | | G = 10 G = 1 | 75 | 90 | | 70 | 75 | | dB |
| INPUT CURRENT | т | $T = 25^{\circ}C$ | | 2 | 10 | | 4 | 20 | |
| Input Bias Current Input Bias Current Drift | I _B TCI _B | $T_A = 25^{\circ}C$ $-40^{\circ}C \le T_A \le +85^{\circ}C$ | | 2 150 | 10 | | 4 250 | 20 | nA pA/°C |
| Input Offset Current Input Offset Current Drift | I _{OS} TCI _{OS} | $T_A = 25^{\circ}C$ $-40^{\circ}C \le T_A \le +85^{\circ}C$ | | 1.2 9 | 5 | | 2 15 | 10 | nA pA/°C |
| INPUT | 1 0105 | | | | | | 15 | | pri c |
| Input Resistance | R _{IN} | Differential, G ≤ 1000 Common Mode, G = 1000 | | 10 16.5 | | | 10 16.5 | | $G\Omega$ $G\Omega$ |
| Input Voltage Range | IVR | $T_A = 25^{\circ}C^1$ | ±11 | 10.5 | | ±11 | 10.5 | | V V |
| Common-Mode Rejection | CMR | $V_{CM} = \pm 11 V$ G = 1000, 100 | 115 | 120 | | 110 | 115 | | dB |
| | | G = 10 | 100 | 115 | | 95 | 110 | | dB |
| | | $G = 1$ $V_{CM} = \pm 11 \text{ V}$ | 80 | 95 | | 75 | 90 | | dB |
| | | $-40^{\circ}C \le T_A \le +85^{\circ}C$ G = 100, 1000 | 110 | 120 | | 105 | 115 | | dB |
| | | G = 10 | 95 | 110 | | 90 | 105 | | dB |
| GAIN | | G = 1 | 75 | 90 | | 70 | 85 | | dB |
| Gain Equation | - 50 kΩ . | G = 1000 | | | 0.50 | | | 0.70 | % |
| Accuracy | $G = \frac{50 \text{ k}\Omega}{R_G} + 1$ | G = 100 G = 10 | | | 0.30 0.25 | | | $0.50 \\ 0.40$ | % % |
| Gain Range | G | G = 1 | 1 | | 0.02 10k | 1 | | 0.05 10k | % V/V |
| Nonlinearity | | G = 1 to 1000 | | 0.006 | | 1 | 0.006 | | % |
| Temperature Coefficient | G _{TC} | $1 \le G \le 1000^{2, 3}$ | | 20 | 50 | | 20 | 50 | ppm/°C |
| OUTPUT RATING Output Voltage Swing | V _{OUT} | $T_A = 25^{\circ}C, R_L = 1 k\Omega$ | ±12 | ±13 | | ±12 | ±13 | | V |
| Positive Current Limit | | $R_L = 1 \text{ k}\Omega, -40^{\circ}\text{C} \le T_A \le +85^{\circ}\text{C}$ Output-to-Ground Short | ±11 | $\frac{\pm 12}{22}$ | | ±11 | $\frac{\pm 12}{22}$ | | V mA |
| Negative Current Limit | | Output-to-Ground Short | | 32 | | | 32 | | mA |
| NOISE Voltage Density, RTI | e _n | $f_0 = 1 \text{ kHz}$ | | | | | | | |
| Voltage Delisity, KII | C _n | G = 1000 | | 9 | | | 9 | | nV/\sqrt{Hz} |
| | | G = 100 G = 10 | | 10 18 | | | 10 18 | | nV/√ <u>Hz</u> nV/√ <u>Hz</u> |
| Noise Current Density, RTI | : | G = 1 $f_0 = 1$ kHz, $G = 1000$ | | 120 0.4 | | | 120 0.4 | | nV/√ <u>Hz</u> pA/√Hz |
| Input Noise Voltage | i _n e _n p-p | 0.1 Hz to 10 Hz | | | | | | | |
| | | G = 1000 G = 100 | | 0.4 0.5 | | | 0.4 0.5 | | μV p-p μV p-p |
| | | G = 10 | | 1.2 | | | 1.2 | | μV p-p |
| DYNAMIC RESPONSE Small-Signal Bandwidth | BW | G = 1 | | 1200 | | | 1200 | | kHz |
| (-3 dB) | WU WU | G = 1 G = 10 | | 300 | | | 300 | | kHz |
| G = 100, 1000 Slew Rate | SR | $G = 10, R_L = 1 k\Omega$ | 4 | 200 6 | | 4 | 200 6 | | kHz V/μs |
| Settling Time | t _S | To $0.01\% \pm 10$ V Step G = 1 to 1000 | | | | | | | · |
| SENSE INPUT | | G = 1 to 1000 | | 10 | | | 10 | | μs |
| Input Resistance | R _{IN} | | | 25 | | | 25 | | kΩ |
| Voltage Range REFERENCE INPUT | | | | ±11 | | | ±11 | | V |
| Input Resistance | R _{IN} | | | 50 | | | 50 | | kΩ |
| Voltage Range Gain to Output | | | | $^{\pm 11}_{1}$ | | | $\frac{\pm 11}{1}$ | | V V/V |

| | | | | AMP02E | | | AMP02F | | |
|--|-----------------------------------|--|------|--------|---|------|--------|-----|---------------|
| Parameter | Symbol | Conditions | Min | Тур | Max | Min | Тур | Max | Unit |
| POWER SUPPLY Supply Voltage Range Supply Current | V _S I _{SY} | $\begin{array}{l} T_{A} = 25^{\circ}C\\ -40^{\circ}C \leq T_{A} \leq +85^{\circ}C \end{array}$ | ±4.5 | 5 5 | $\begin{array}{c}\pm 18\\6\\6\end{array}$ | ±4.5 | 5 5 | | V mA mA |

NOTES

¹Input voltage range guaranteed by common-mode rejection test.

²Guaranteed by design.

³Gain tempco does not include the effects of external component drift.

Specifications subject to change without notice.

ABSOLUTE MAXIMUM RATINGS^{1, 2}

| Supply Voltage | $\pm 18 \text{ V}$ |
|--------------------------------|--------------------------------|
| Common-Mode Input Voltage | [(V–) – 60 V] to [(V+) + 60 V] |
| Differential Input Voltage | [(V–) – 60 V] to [(V+) + 60 V] |
| Output Short-Circuit Duration | Continuous |
| Operating Temperature Range | -40°C to +85°C |
| Storage Temperature Range | −65°C to +150°C |
| Function Temperature Range | −65°C to +150°C |
| Lead Temperature (Soldering, 1 | 10 sec) 300°C |
| | |

| Package Type | $\theta_{JA}{}^3$ | θ_{JC} | Unit |
|------------------------|-------------------|---------------|------|
| 8-Lead Plastic DIP (P) | 96 | 37 | °C/W |
| 16-Lead SOIC (S) | 92 | 27 | °C/W |

NOTES

¹Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

²Absolute maximum ratings apply to both DICE and packaged parts, unless otherwise noted.

 ${}^{3}\theta_{JA}$ is specified for worst case mounting conditions, i.e., θ_{JA} is specified for device in socket for P-DIP package; θ_{JA} is specified for device soldered to printed circuit board for SOIC package.

ORDERING GUIDE

| Model | $V_{IOS} \max @$ $T_A = 25^{\circ}C$ | | Temperature Range | Package Description |
|---|---|-------------------------------|---|--|
| AMP02EP AMP02FP AMP02AZ/883C AMP02FS AMP02GBC | 100 μV 200 μV 200 μV 200 μV | 4 mV 8 mV 10 mV 8 mV | -40°C to +85°C -40°C to +85°C -55°C to +125°C -40°C to +85°C | 8-Lead Plastic DIP 8-Lead Plastic DIP 8-Lead CERDIP 16-Lead SOIC Die |
| AMP02FS-REEL | 200 µV | 8 mV | -40°C to +85°C | 16-Lead SOIC |

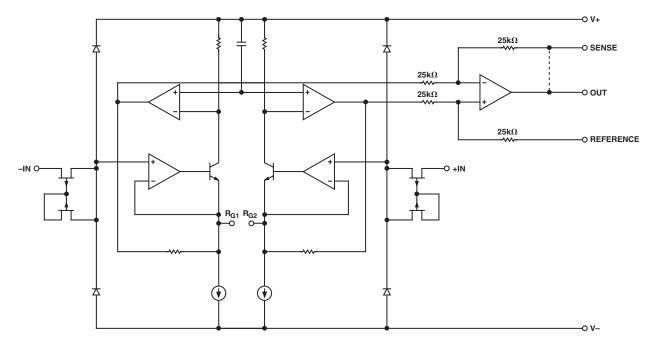
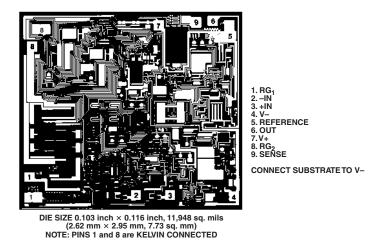


Figure 2. Simplified Schematic



Die Characteristics

WAFER TEST LIMITS* (@ $V_S = \pm 15 V$, $V_{CM} = 0 V$, $T_A = 25^{\circ}C$, unless otherwise noted.)

| Parameter | Symbol | Conditions | AMP02 GBC Limits | Unit |
|---------------------------|------------------|--|------------------------|--------|
| Input Offset Voltage | V _{IOS} | | 200 | μV max |
| Output Offset Voltage | V _{oos} | | 8 | mV max |
| Power Supply Rejection | PSR | $V_{S} = \pm 4.8 V \text{ to } \pm 18 V$ G = 1000 G = 100 G = 10 G = 1 | 110 110 95 75 | dB |
| Input Bias Current | I _B | | 20 | nA max |
| Input Offset Current | I _{OS} | | 10 | nA max |
| Input Voltage Range | IVR | Guaranteed by CMR Tests | ±11 | V min |
| Common-Mode Rejection | CMR | $V_{CM} = \pm 11 V$ G = 1000 G = 100 G = 10 G = 1 | 110 110 95 75 | dB |
| Gain Equation Accuracy | | $G = \frac{50 \text{ k}\Omega}{R_{\rm G}} + 1, G = 1000$ | 0.7 | % max |
| Output Voltage Swing | V _{OUT} | $R_L = 1 k\Omega$ | ±12 | V min |
| Supply Current | I _{SY} | | 6 | mA max |

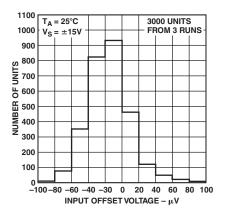
*Electrical tests are performed at wafer probe to the limits shown. Due to variations in assembly methods and normal yield loss, yield after packaging is not guaranteed for standard product dice. Consult factory to negotiate specifications based on dice lot qualifications through sample lot assembly and testing.

CAUTION _

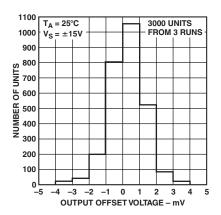
ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AMP02 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



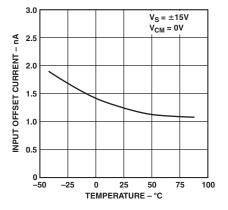
Typical Performance Characteristics–AMP02



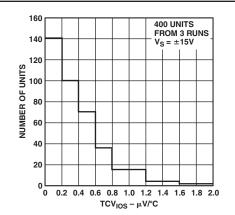
TPC 1. Typical Distribution of Input Offset Voltage



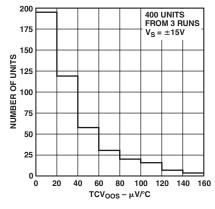
TPC 4. Typical Distribution of Output Offset Voltage



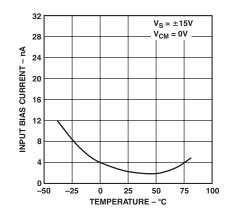
TPC 7. Input Offset Current vs. Temperature



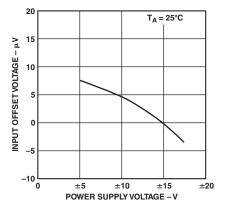
TPC 2. Typical Distribution of TCV_{IOS}



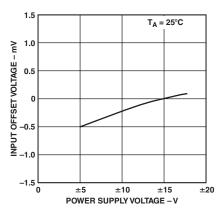
TPC 5. Typical Distribution of TCV_{00S}



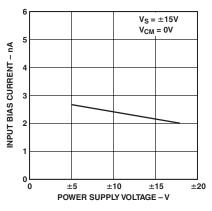
TPC 8. Input Bias Current vs. Temperature



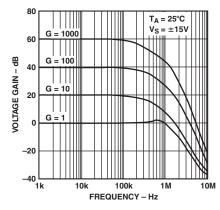
TPC 3. Input Offset Voltage Change vs. Supply Voltage



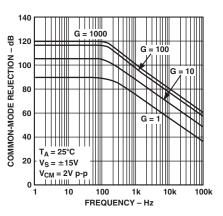
TPC 6. Output Offset Voltage Change vs. Supply Voltage



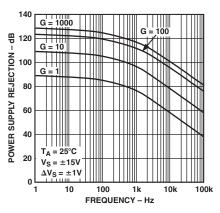
TPC 9. Input Bias Current vs. Supply Voltage



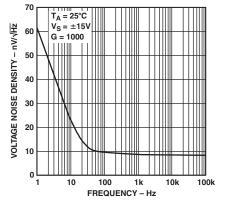
TPC 10. Closed-Loop Voltage Gain vs. Frequency



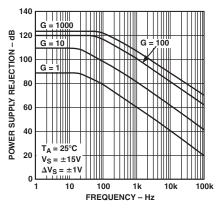
TPC 11. Common-Mode Rejection vs. Frequency



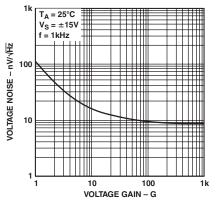
TPC 13. Positive PSR vs. Frequency



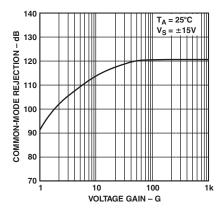
TPC 16. Voltage Noise Density vs. Frequency



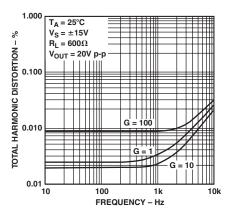
TPC 14. Negative PSR vs. Frequency



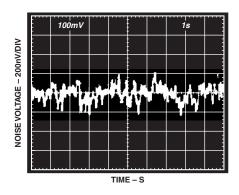
TPC 17. RTI Voltage Noise Density vs. Gain



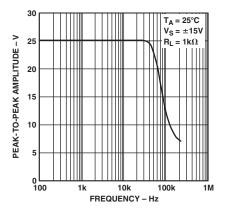
TPC 12. Common-Mode Rejection vs. Voltage Gain



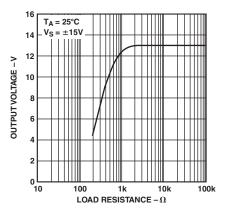
TPC 15. Total Harmonic Distortion vs. Frequency



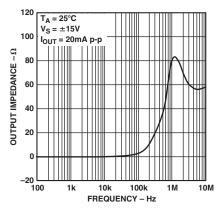
TPC 18. 0.1 Hz to 10 Hz Noise $A_V = 1000$



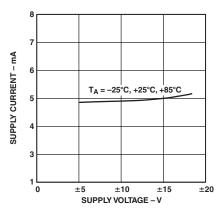
TPC 19. Maximum Output Swing vs. Frequency



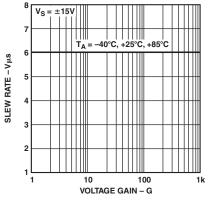
TPC 20. Maximum Output Voltage vs. Load Resistance



TPC 21. Closed Loop Output Impedance vs. Frequency



TPC 22. Supply Current vs. Supply Voltage



TPC 23. Slew Rate vs. Voltage Gain

APPLICATIONS INFORMATION

Input and Output Offset Voltages

Instrumentation amplifiers have independent offset voltages associated with the input and output stages. The input offset component is directly multiplied by the amplifier gain, whereas output offset is independent of gain. Therefore at low gain, output-offset errors dominate while at high gain, input-offset errors dominate. Overall offset voltage, V_{OS} , referred to the output (*RTO*) is calculated as follows:

$$V_{OS}(RTO) = (V_{IOS} \times G) + V_{OOS}$$

where V_{IOS} and V_{OOS} are the input and output offset voltage specifications and G is the amplifier gain.

The overall offset voltage drift TCV_{OS} , referred to the output, is a combination of input and output drift specifications. Input offset voltage drift is multiplied by the amplifier gain, G, and summed with the output offset drift:

$$TCV_{OS}(RTO) = (TCV_{IOS} \times G) + TCV_{OOS}$$

where TCV_{IOS} is the input offset voltage drift, and TCV_{OOS} is the output offset voltage drift. Frequently, the amplifier drift is referred back to the input (*RTI*), which is then equivalent to an input signal change:

$$TCV_{OS}\left(RTI\right) = TCV_{IOS} + \frac{TCV_{OOS}}{G}$$

For example, the maximum input-referred drift of an AMP02EP set to G = 1000 becomes:

$$TCV_{OS}(RTI) = 2 \,\mu V/^{\circ}C + \frac{100 \,\mu V/^{\circ}C}{1000} = 2.1 \,\mu V/^{\circ}C$$

Input Bias and Offset Currents

Input transistor bias currents are additional error sources that can degrade the input signal. Bias currents flowing through the signal source resistance appear as an additional offset voltage. Equal source resistance on both inputs of an IA will minimize offset changes due to bias current variations with signal voltage and temperature; however, the difference between the two bias currents (the input offset current) produces an error. The magnitude of the error is the offset current times the source resistance.

A current path must always be provided between the differential inputs and analog ground to ensure correct amplifier operation. Floating inputs such as thermocouples should be grounded close to the signal source for best common-mode rejection.

Gain

The AMP02 only requires a single external resistor to set the voltage gain. The voltage gain, G, is:

$$G = \frac{50 \, k\Omega}{R_G} + 1$$

and

$$R_G = \frac{50 \, k\Omega}{G - 1}$$

The voltage gain can range from 1 to 10,000. A gain set resistor is not required for unity-gain applications. Metal-film or wirewound resistors are recommended for best results.

The total gain accuracy of the AMP02 is determined by the tolerance of the external gain set resistor, R_G , combined with the gain equation accuracy of the AMP02. Total gain drift combines the mismatch of the external gain set resistor drift with that of the internal resistors (20 ppm/°C typ). Maximum gain drift of the AMP02 independent of the external gain set resistor is 50 ppm/°C.

All instrumentation amplifiers require attention to layout so thermocouple effects are minimized. Thermocouples formed between copper and dissimilar metals can easily destroy the TCV_{OS} performance of the AMP02, which is typically 0.5 μ V/°C. Resistors themselves can generate thermoelectric EMFs when mounted parallel to a thermal gradient.

The AMP02 uses the triple op amp instrumentation amplifier configuration with the input stage consisting of two transimpedance amplifiers followed by a unity-gain differential amplifier. The input stage and output buffer are laser-trimmed to increase gain accuracy. The AMP02 maintains wide bandwidth at all gains as shown in Figure 3. For voltage gains greater than 10, the bandwidth is over 200 kHz. At unity gain, the bandwidth of the AMP02 exceeds 1 MHz.

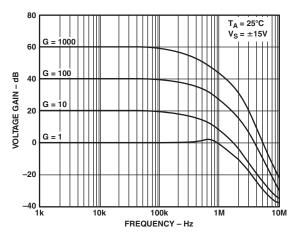


Figure 3. The AMP02 Keeps Its Bandwidth at High Gains

Common-Mode Rejection

Ideally, an instrumentation amplifier responds only to the difference between the two input signals and rejects common-mode voltages and noise. In practice, there is a small change in output voltage when both inputs experience the same common-mode voltage change; the ratio of these voltages is called the common-mode gain. Common-mode rejection (CMR) is the logarithm of the ratio of differential-mode gain to common-mode gain, expressed in dB. Laser trimming is used to achieve the high CMR of the AMP02.

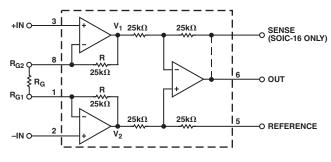


Figure 4. Triple Op Amp Topology

Figure 4 shows the triple op amp configuration of the AMP02. With all instrumentation amplifiers of this type, it is critical not to exceed the dynamic range of the input amplifiers. The amplified differential input signal and the input common-mode voltage must not force the amplifier's output voltage beyond ± 12 V (V_s = ± 15 V) or nonlinear operation will result.

The input stage amplifier's output voltages at V_1 and V_2 equal:

$$V_1 = -\left(1 + \frac{2R}{R_G}\right)\frac{V_D}{2} + V_{CM}$$
$$= -G\frac{V_D}{2} + V_{CM}$$
$$V_2 = \left(1 + \frac{2R}{R_G}\right)\frac{V_D}{2} + V_{CM}$$
$$= G\frac{V_D}{2} + V_{CM}$$

where:

 V_D = Differential input voltage

$$= (+IN) - (-IN)$$

 V_{CM} = Common-mode input voltage

G = Gain of instrumentation amplifier

If V_1 and V_2 can equal ± 12 V maximum, the common-mode input voltage range is:

$$CMVR = \pm \left(12 V - \frac{GV_D}{2}\right)$$

Grounding

The majority of instruments and data acquisition systems have separate grounds for analog and digital signals. Analog ground may also be divided into two or more grounds that will be tied together at one point, usually at the analog power supply ground. In addition, the digital and analog grounds may be joined—normally at the analog ground pin on the A/D converter. Following this basic practice is essential for good circuit performance.

Mixing grounds causes interactions between digital circuits and the analog signals. Since the ground returns have finite resistance and inductance, hundreds of millivolts can be developed between the system ground and the data acquisition components. Using separate ground returns minimizes the current flow in the sensitive analog return path to the system ground point. Consequently, noisy ground currents from logic gates interact with the analog signals.

Inevitably, two or more circuits will be joined together with their grounds at differential potentials. In these situations, the differential input of an instrumentation amplifier, with its high CMR, can accurately transfer analog information from one circuit to another.

Sense and Reference Terminals

The sense terminal completes the feedback path for the instrumentation amplifier output stage and is internally connected directly to the output. For SOIC devices, connect the sense terminal to the output. The output signal is specified with respect to the reference terminal, which is normally connected to analog ground. The reference may also be used for offset correction level shifting. A reference source resistance will reduce the common-mode rejection by the ratio of 25 k Ω/R_{REF} . If the reference source resistance is 1 Ω , the CMR will be reduced 88 dB (25 k $\Omega/1 \Omega$ = 88 dB).

Overvoltage Protection

Instrumentation amplifiers invariably sit at the front end of instrumentation systems where there is a high probability of exposure to overloads. Voltage transients, failure of a transducer, or removal of the amplifier power supply while the signal source is connected may destroy or degrade the performance of an unprotected device. A common technique is to place limiting resistors in series with each input, but this adds noise. The AMP02 includes internal protection circuitry that limits the input current to ± 4 mA for a 60 V differential overload (see Figure 5) with power off, ± 2.5 mA with power on.

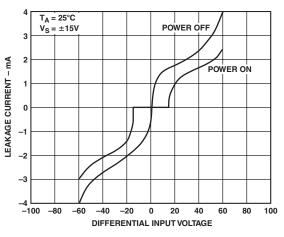


Figure 5. AMP02's Input Protection Circuitry Limits Input Current During Overvoltage Conditions

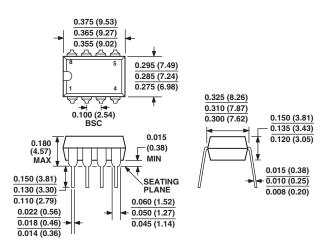
Power Supply Considerations

Achieving the rated performance of precision amplifiers in a practical circuit requires careful attention to external influences. For example, supply noise and changes in the nominal voltage directly affect the input offset voltage. A PSR of 80 dB means that a change of 100 mV on the supply (not an uncommon value) will produce a 10 μ V input offset change. Consequently, care should be taken in choosing a power unit that has a low output noise level, good line and load regulation, and good temperature stability. In addition, each power supply should be properly bypassed.

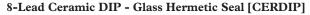
OUTLINE DIMENSIONS

8-Lead Plastic Dual-in-Line Package [PDIP] (N-8)

Dimensions shown in inches and (millimeters)

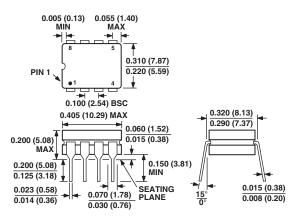


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(Q-8)

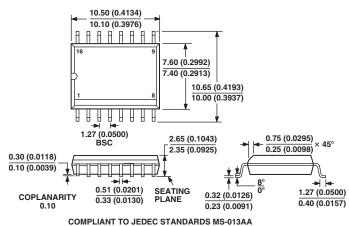
Dimensions shown in inches and (millimeters)

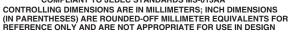


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16-Lead Standard Small Outline Package [SOIC] Wide Body (R-16)

Dimensions shown in millimeters and (inches)





Revision History

| Location | Page |
|--|------|
| 1/03—Data Sheet changed from REV. D to REV. E. | |
| Edits to Figure 2 | 3 |
| Edits to Die Characteristics | 4 |
| Updated OUTLINE DIMENSIONS | |

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